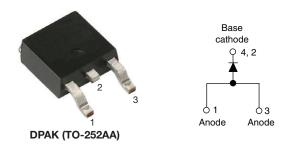
Vishay Semiconductors

High Performance Schottky Rectifier, 10 A



www.vishay.com

PRIMARY CHARACTERISTICS					
I _{F(AV)}	10 A				
V _R	45 V				
V _F at I _F	0.53 V				
I _{RM}	15 mA at 125 °C				
T _J max.	175 °C				
E _{AS}	20 mJ				
Package	DPAK (TO-252AA)				
Circuit configuration	Single				

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Popular DPAK (TO-252AA) outline
- Small foot print, surface mountable
- High frequency operation
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10WQ045FNHM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	10	А				
V _{RRM}		45	V				
I _{FSM}	t _p = 5 μs sine	400	А				
V _F	10 A _{pk} , T _J = 125 °C	0.53	V				
TJ	Range	-40 to +175	°C				

VOLTAGE RATINGS			
PARAMETER	SYMBOL	VS-10WQ045FNHM3	UNITS
Maximum DC reverse voltage	V _R	45	V
Maximum working peak reverse voltage	V _{RWM}	45	v

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 157 °C, rectangular waveform		10	А		
Maximum peak one cycle non-repetitive surge current	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	400	A		
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	75			
Non-repetitive avalanche energy	E _{AS}	$T_{\rm J} = 25 {}^{\circ}\text{C}, I_{\rm AS} = 3 \text{A}, L = 4.4 \text{mH}$		20	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3.0	А		

Revision: 03-Aug-2023 1 Document Number: 94737 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>





Vishay Semiconductors

FL	ЕСТ	BIC	ΔΙ S	SDE	CIEI	гаті	ONS
			AL \	7F 6		/A I I	

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS	
		10 A	T.I = 25 °C	0.63	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	20 A	1j=25 0	0.80		
See fig. 1	VFM ("	10 A	T 105.00	0.53		
		20 A	T _J = 125 °C	0.71		
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = rated $V_{\rm B}$	1	mA	
See fig. 2	IRM ("	T _J = 125 °C	$v_{\rm R} = rateu v_{\rm R}$	15		
Threshold voltage	V _{F(TO)}	T T maximum	0.255	V		
Forward slope resistance	r _t	$T_{\rm J} = T_{\rm J}$ maximum 22 ms				
Typical junction capacitance	CT	$V_{\rm R}$ = 5 $V_{\rm DC}$ (test signal range 100 kHz to 1 MHz), 25 °C 760 pF			pF	
Typical series inductance	L _S	Measured lead to lead 5 m	m from package body	5.0	nH	

Note

Γ

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +175	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	2.0	°C/W		
Maximum thermal resistance, junction to ambient	R _{thJA}		50	-C/W		
Approximate weight			0.3	g		
Approximate weight			0.01	oz.		
Marking device		Case style DPAK (TO-252AA)	10WQ0	45FNH		

Note

⁽¹⁾ $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink



VS-10WQ045FNHM3

Vishay Semiconductors

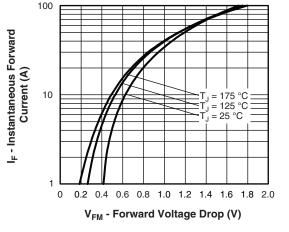


Fig. 1 - Maximum Forward Voltage Drop Characteristics

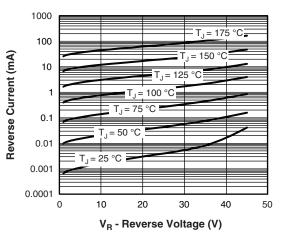


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

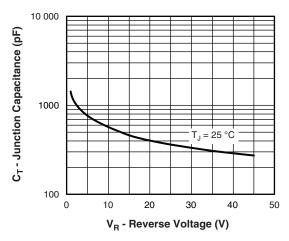
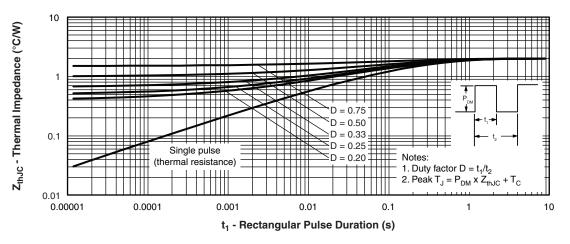


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





 Revision: 03-Aug-2023
 Document Number: 94737

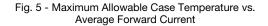
 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesEurope@vishay.com

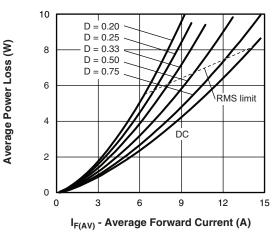
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



180 Allowable Case Temperature (°C) 170 DC 160 Square wave (D = 0.50)80 % rated $\rm V_{R}$ applied 150 See note (1) 140 0 2 4 6 8 10 12 14 16

I_{F(AV)} - Average Forward Current (A)







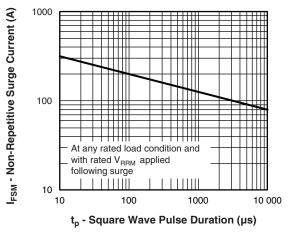


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC};$ Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R (1 - D); I_R$ at $V_{R1} = 80 \%$ rated V_R VS-10WQ045FNHM3

Vishay Semiconductors

Vishay Semiconductors

ORDERING INFORMATION TABLE

www.vishay.com

VISHAY

Device code	VS-	10	w	Q	045	FN	TRL	Н	М3
	1	2	3	4	5	6	7	8	9
	1	- Visł	nay Sen	niconduc	ctors pro	oduct			
	2	- Cur	rent rati	ng (10 A	4)				
	3	- Pac	kage id	entifier:					
	_		DPAK						
		- Sch	ottky "C)" series	i				
	5	- Volt	age rati	ng (045	= 45 V)				
	6	- FN	= TO-2	52AA (D	PAK)				
	7	• N	one = T	ube					
		• TI	R = Tap	e and re	el				
		• TF	RL = Ta	pe and r	reel (left	oriente	d)		
		• TF	RR = Ta	pe and	reel (rigl	nt orien	ted)		
	8	- H=	AEC-Q	101 qua	alified				
	9			ntal digit en-free,	: RoHS-	complia	int, and	termina	tions le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10WQ045FNHM3	75	3000	Antistatic plastic tube					
VS-10WQ045FNTRHM3	2000	2000	13" diameter reel					
VS-10WQ045FNTRRHM3	3000	3000	13" diameter reel					
VS-10WQ045FNTRLHM3	3000	3000	13" diameter reel					

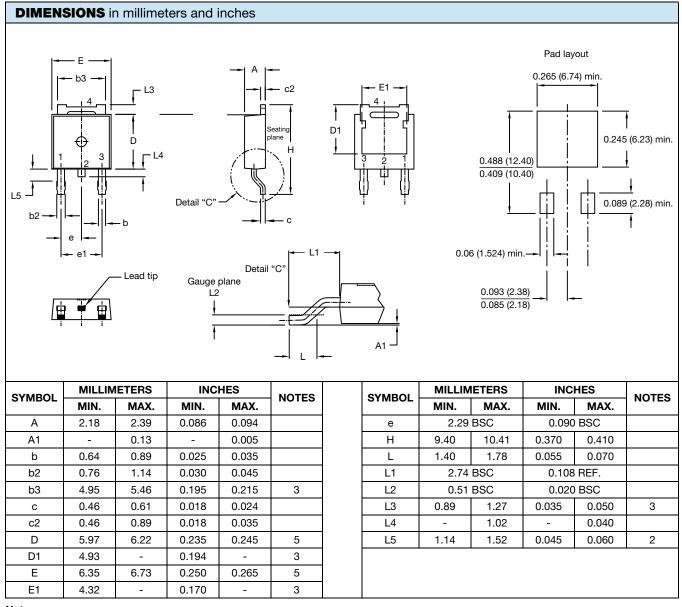
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95519				
Part marking information	www.vishay.com/doc?95518				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?96555				

Outline Dimensions



Vishay Semiconductors

DPAK (TO-252AA)



Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Dimensions D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁵⁾ Outline conforms to JEDEC[®] outline TO-252AA, except for D1 dimension



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.